

1. Descriptions

The KP3528R64A1I-PF is a small and thin form plastic leaded chip carrier(PLCC) 2-pin package with AlInGaP Red LED.

2. Features

- ◆ Small Footprint Surface Mount Package (3.5 L × 2.8 W × 1.9 H [mm])
- ◆ Typical Forward Voltage(V_F) : 2.2 V @ Forward Current(I_F)=20mA
- ◆ Operation Temperature from -40℃ to +100℃
- ◆ Soldering methods : IR reflow soldering
- ◆ Taping : 8mm conductive black carrier tape & antistatic clear cover tape

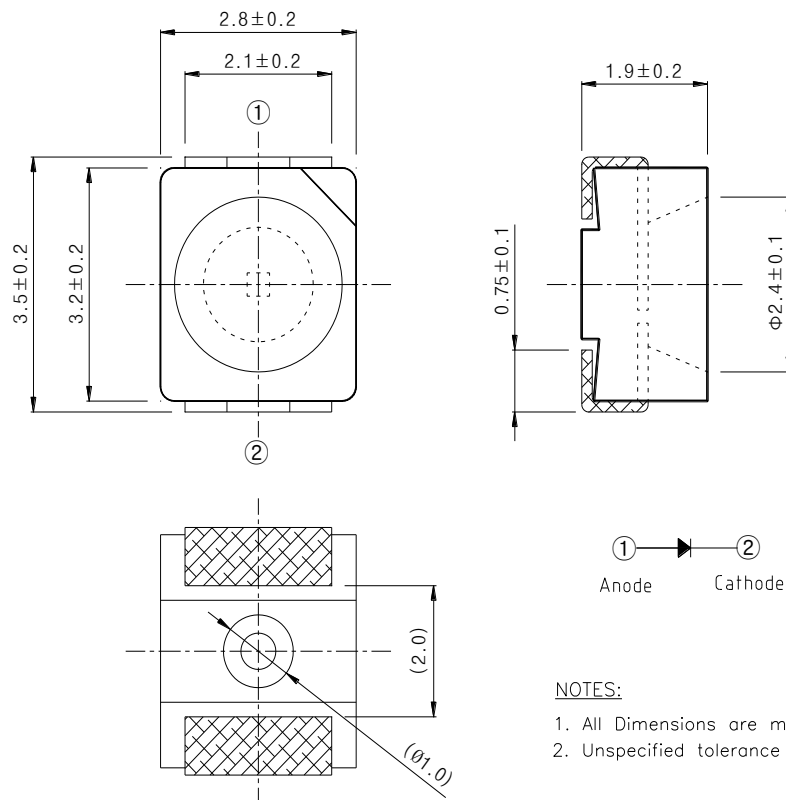
3. Applications

- ◆ Interior lighting
- ◆ General lighting
- ◆ Indoor and out door displays
- ◆ Architectural / Decorative lighting

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When using this product, would you please refer to the latest specifications.

4. Outline Dimensions and Material Descriptions

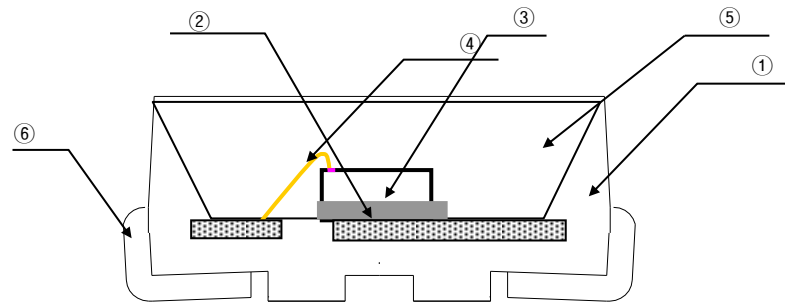
◆ Outline Dimensions



NOTES:

1. All Dimensions are millimeters
2. Unspecified tolerance : ± 0.2

◆ Material Descriptions



No.	ITEM	Material
①	Frame Resin	Polyamide
②	Paste	Ag Epoxy
③	LED Chip	AlInGaP
④	Wire	Au
⑤	Encapsulant	Clear Silicone
⑥	Electrode	Cu alloy

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5. Absolute Maximums

Item	Symbol	Min.	Max.	Unit	Conditions
Forward Current	I_F	-	30	mA	
Peak Forward Current ^{*1}	I_{FP}	-	60	mA	
Power Dissipation	P_D	-	72	mW	
Reverse Voltage	V_R	9	-	V	
Operating Temperature	T_{OP}	-40	100	°C	
Storage Temperature	T_S	-40	100	°C	
Soldering Temperature ^{*2}	T_{sol}	-	260	°C	

*1. IFP was measured at $T_w \leq 1$ msec of pulse width and $D \leq 1/10$ of duty ratio.

*2. Soldering time : 5 Sec

6. Electro-Optical Characteristics ($T_A = 25^\circ\text{C}$)

Item	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage ^{*3}	V_F	1.7	-	2.5	V	$I_F=20\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R=5\text{V}$
Luminous intensity [*] 1,3	I_V	150	-	650	mcd	$I_F=20\text{mA}$
Dominant wavelength	λ_D	635	-	645	nm	$I_F=20\text{mA}$
Half angle ^{*2}	$2\theta_{1/2}$	-	120	-	deg	$I_F=20\text{mA}$

*1. The luminous intensity I_V was measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package.

*2. $2\theta_{1/2}$ is the off-axis where the luminous intensity is 1/2 of the peak intensity.

*3. Measuring Tolerance

- $V_F : \pm 0.1 \text{ V}$, $I_V : \pm 10\%$, $R_a : \pm 3$, $X, Y : \pm 0.01$

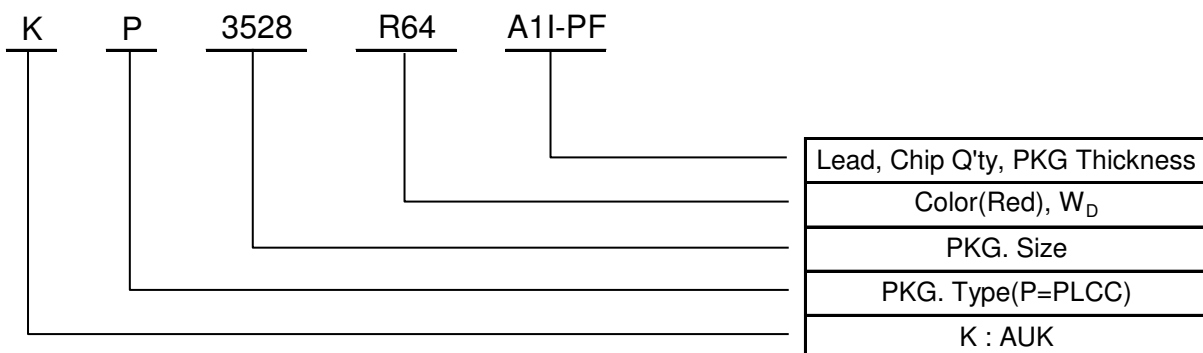
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7. Ranks

◆ V_F, I_V, W_D @ $I_F = 20 \text{ mA}$

Forward Voltage [V]	Luminuous Intensity [mcd]	Wavelength [nm]
1 : 1.7 ~ 2.1	O : 150 ~ 250	a : 635 ~ 637
2 : 2.1 ~ 2.5	P : 250 ~ 350	b : 637 ~ 639
X	Q : 350 ~ 450	c : 639 ~ 641
X	R : 450 ~ 550	d : 641 ~ 643
X	S : 550 ~ 650	e : 643 ~ 645

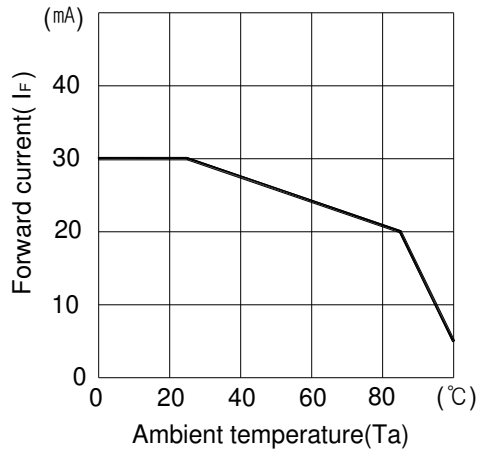
8. Part Numbering



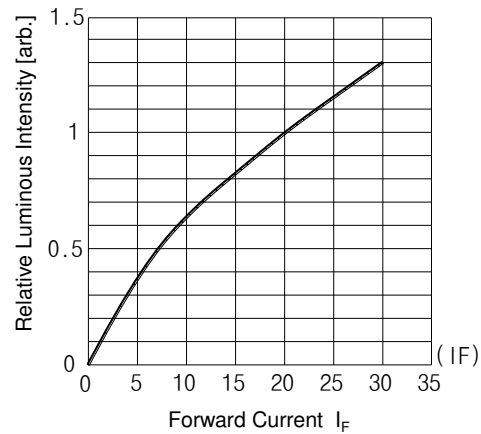
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9. Characteristic Graphs

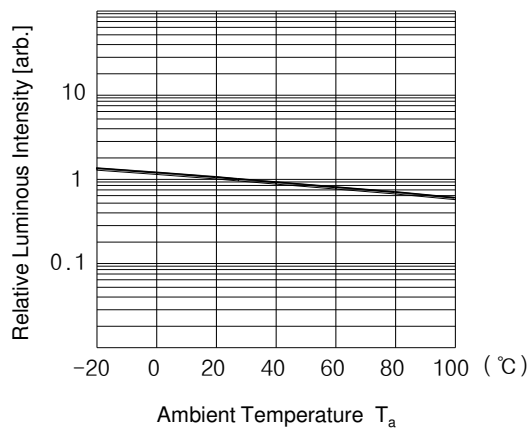
**Forward Current Vs
Ambient Temperature**



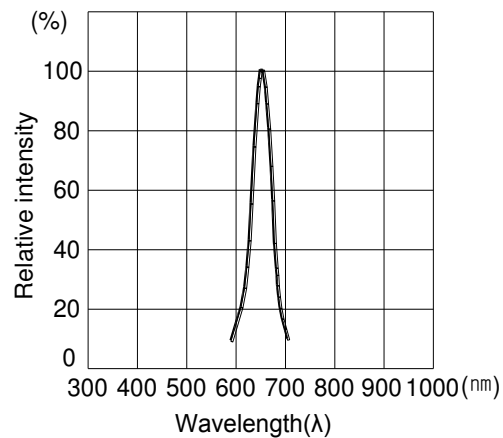
**Relative Luminous Intensity vs.
Forward Current**



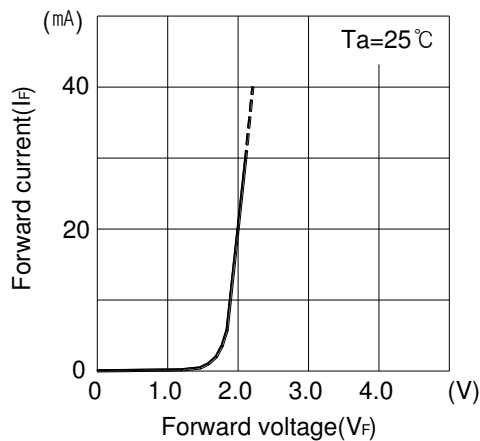
**Relative luminous Intensity vs.
Ambient Temperature**



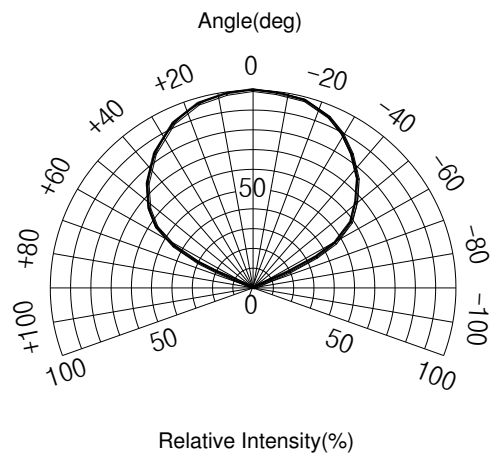
**Relative Intensity vs.
Wavelength**



**Forward Current vs.
Forward Voltage**



Radiant Pattern



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